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GOODRAM Industrial microSD Memory Card pSLC type DATASHEET

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microSD Card for Industrial Applications

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GOODRAM Industrial pSLC microSD

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REVISION HISTORY

VERSION	CHANGES	DATE
1.0	Initial release	31.10.2017
1.1	Add 64GB pSLC	06.09.2017
1.2	Logo amendment	06.12.2017
1.3	Added 1GB capacity	12.10.2018
1.4	Logo amendment	14.12.2023

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PRODUCT OVERVIEW

- | | |
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| <ul style="list-style-type: none"> Capacity: <ul style="list-style-type: none"> o pSLC: 1GB – 64GB Flash Type <ul style="list-style-type: none"> o MLC ^{Note1} Speed Class <ul style="list-style-type: none"> o 2GB: Non-UHS o 4GB - 64GB: UHS-I Power Consumption <ul style="list-style-type: none"> o Power Up Current < 250uA o Standby Current < 1000uA o Read Current < 400mA o Write Current < 400mA Performance <ul style="list-style-type: none"> o Read: min 95MB/s o Write: min 90MB/s MTBF <ul style="list-style-type: none"> o More than 3 000 000 hours Support SD system specification version 3.0 The Command List supports: “Part 1 Physical Layer Specification Ver 3.01 Final definition”. RoHS compliant | <ul style="list-style-type: none"> Endurance <ul style="list-style-type: none"> o 20000 erase/program cycles in whole capacity o Data retention over 10 years in room temperature (250°C) ^{Note2} Copyrights Protection Mechanisms – Complies with highest security CPRM standard Support CPRM Support SD SPI mode Advanced Flash Management <ul style="list-style-type: none"> o Static and Dynamic Wear Levelling o Bad Block Management o SMART Function ^{Note3} o Auto-Read Refresh o Embedded Mode ^{Note3} Operating Voltage range <ul style="list-style-type: none"> o 2.7 – 3.6 V Temperature Range ^{Note4} <ul style="list-style-type: none"> o Operation <ul style="list-style-type: none"> o Gold: -25°C — +85°C o Diamond: -40°C — +85°C o Storage: -40°C — +85°C |
|--|--|

Notes:

1. Pseudo SLC can be considered as an extended version of MLC.
2. In new product
3. This function is enabled by customer requirement.
4. According to IEC-60068-2-1/2/14/38 standard.

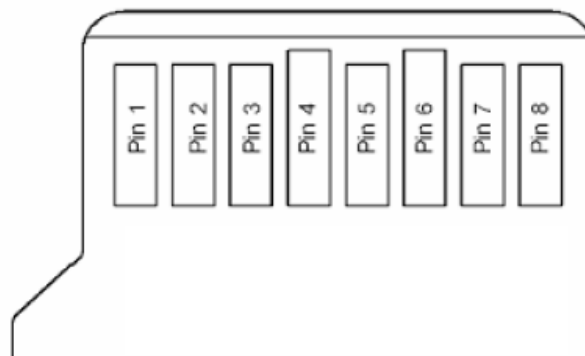
PRODUCT DETAILS

GENERAL DESCRIPTION

The Micro Secure Digital (microSD) card version 3.0 is fully compliant to the specification released by SD Card Association. The Command List supports [Part 1 Physical Layer Specification Ver3.01 Final] definitions. Card Capacity of Non-secure Area, Secure Area Supports [Part 3 Security Specification Ver3.0 Final] Specifications.

The microSD 3.0 card is based on 8-pin interface, designed to operate at a maximum operating frequency of 208MHz. It can alternate communication protocol between the SD mode and SPI mode. It performs data error detection and correction with very low power consumption.

PIN ASSIGNMENT MICROSD CARD



PIN	SD MODE			SPI MODE		
	NAME	TYPE	DESCRIPTION	NAME	TYPE	DESCRIPTION
1	DAT2	I/O/PP	Data Line [bit2]	RSV		
2	CD/DAT3	I/O/PP	Card Detect/ Data Line [bit3]	CS	I	Chip Select (neg true)
3	CMD	PP	Command/Response	DI	I	Data In
4	VDD	S	Supply Voltage	VDD	S	Supply voltage
5	CLK	I	Clock	SCLK	I	Clock
6	VSS	S	Supply voltage ground	VSS	S	Supply voltage ground
7	DAT0	I/O/PP	Data Line [bit0]	DO	O/PP	Data Out
8	DAT1	I/O/PP	Data Line [bit1]	RSV		

FLASH MANAGEMENT

GOODRAM microSD card utilizes all the state of art technologies to ensure full reliability until the specified NAND Flash program/erase cycles parameter is reached. These technologies include but are not limited to:

Error Correction Code (ECC)

Flash memory cells will deteriorate with use, which may generate random bit errors in the stored data. To ensure the highest reliability, GOODRAM microSD card applies the BCH ECC Algorithm, which can detect and correct errors that occur during read process, to ensure data is read correctly, as well as protected from corruption.

Wear Levelling

Storage devices based on NAND flash memory, can only undergo a limited number of program/erase cycles, and due to various usage scenarios, data may not be distributed evenly between NAND flash chips. If a certain area gets updated more frequently than others, the lifetime of the device will be reduced significantly. Wear Leveling algorithm used in GOODRAM microSD cards is used to extend the lifespan of NAND Flash by evenly distributing write and erase cycles across the whole storage area. Moreover, by utilizing both dynamic and static Wear Leveling algorithms, the life expectancy of GOODRAM microSD cards can meet the listed specification.

Bad Block Management

Bad blocks are blocks that include one or more invalid bits, and their reliability is not guaranteed. Blocks that are identified and marked as bad by the manufacturer are referred to as “Initial Bad Blocks”. Bad blocks that are developed during the lifespan of the flash are named “Later Bad Blocks”. GOODRAM microSD card uses an efficient bad block management algorithm to detect all types of bad blocks, which further prevents data being stored into them and improves the data reliability.

SMART Function

SMART, an acronym for Self-Monitoring, Analysis and Reporting Technology, is a special function that allows a memory device automatically monitor its health.

Auto-Read Refresh

Auto-Read Refresh is especially applied on devices that read data mostly but rarely write data. When blocks are continuously read, then the device cannot activate wear leveling since it can only be applied while writing data. Thus, errors will accumulate and become uncorrectable. Accordingly, to avoid errors exceed the amount ECC can correct and blocks turn bad, firmware will automatically refresh the bit errors when the error number in one block approaches the threshold, ex. 24 bits.

Embedded Mode

Embedded mode is a function specially designed for operating systems that not utilize FAT. Often under non Windows OS, for example Linux or customized host, wear leveling mechanism will be affected or even disabled in some cases. With embedded mode activated, wear leveling mechanism can operate normally to keep the usage of blocks even throughout the card's life cycle.

Pseudo SLC

Pseudo SLC can be considered as an extended version of MLC. While MLC contains fast and slow pages, pSLC only applies fast pages for programming. The concept of pSLC is demonstrated in the two tables below. Because only fast pages are programmed, pSLC provide better performance and endurance than MLC.

MLC Flash		→	Pseudo SLC Flash	
1st Bit (Fast page)	2nd Bit (Slow page)		1st Bit (Fast page)	2nd Bit (Slow page)
1	1		1	1
1	0		1	0
0	1		0	1
0	0		0	0

COMPARING SD3.0, SDHC AND SDXC

	SD3.0 Standard (Backward compatible to 2.0 host)	SD3.0 SDHC/SDXC (Backward compatible to 2.0 host)
Addressing Mode	Byte (1 byte unit)	Block (512 byte unit)
HCS/CCS bits of ACMD41	Support	Support
CMD8 (SEND_IF_COND)	Support	Support
CMD16 (SET_BLOCKLEN)	Support	Support (Only CMD42)
Partial Read	Support	Not Support
Lock/Unlock Function	Mandatory	Mandatory
Write Protect Groups	Optional	Not Support
Supply Voltage 2.0v – 2.7v (for initialization)	Not Support	Not Support
Total Bus Capacitance for each signal line	40pF	40pF
CSD Version (CSD_STRUCTURE Value)	1.0 (0x0)	2.0 (0x1)
Speed Class	Optional	Mandatory (Class 2/4/6/10)

PERFORMANCE

Process	Capacity	Mode	Flash Structure	Sequential	
				Read (MB/s)	Write (MB/s)
A19nm	1GB	Non-UHS	2GB x 1, SIP	20	20
	2GB	Non-UHS	2GB x 1, SIP	20	20
	4GB	UHS-I	4GB x 1, SIP	90	80
	8GB	UHS-I	8GB x 1, SIP	95	90
	16GB	UHS-I	8GB x 2, SIP	95	90
	32GB	UHS-I	8GB x 4, SIP	95	90
15nm	1GB	Non-UHS	2GB x 1, SIP	20	20
	2GB	Non-UHS	2GB x 1, SIP	20	20
	4GB	UHS-I	4GB x 1, SIP	90	80
	8GB	UHS-I	8GB x 1, SIP	95	90
	16GB	UHS-I	8GB x 2, SIP	95	90
	32GB	UHS-I	8GB x 4, SIP	95	90
	64GB	UHS-I	8GB x 8, SIP	95	90

ELECTRICAL SPECIFICATIONS

Capacity	Read (mA)	Write (mA)	Idle (uA)
1GB – 32GB	400	400	1000

Note:

1. Performance may vary from flash configuration and platform.
2. The table above is for your reference only. The criteria for mass production and for accepting goods shall be discussed based on different flash configuration.

PARAMETER	RATING
Operating voltage	2.7 – 3.6V +/- 5%

Temperature specification

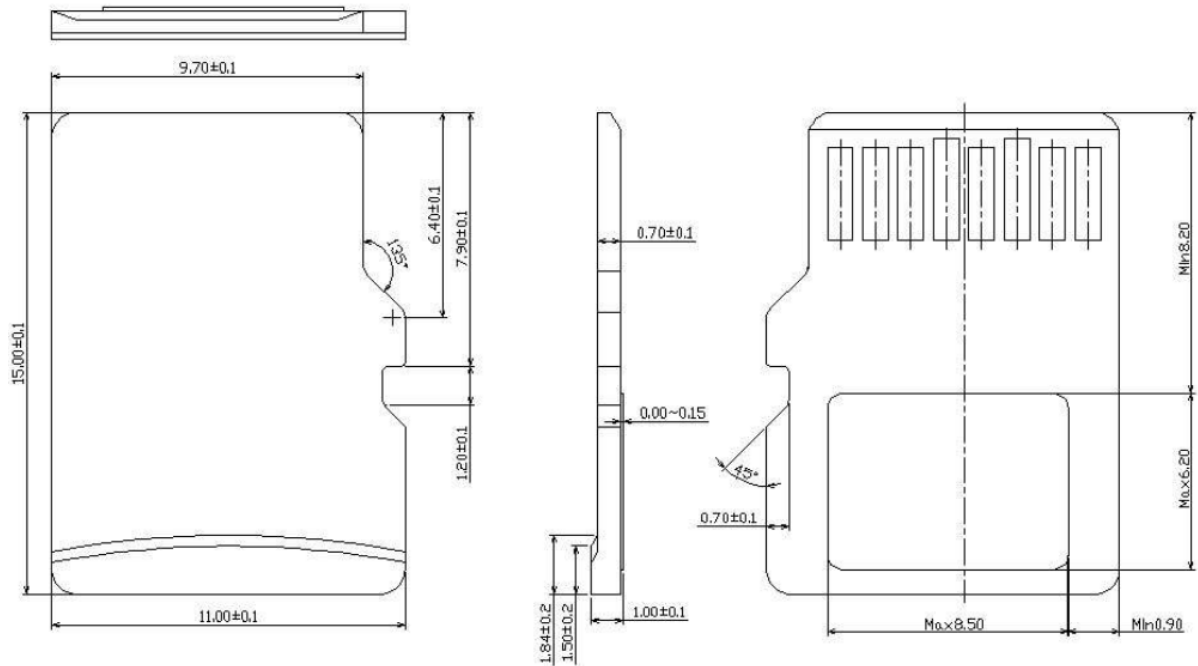
SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T _a	Operating Temperature Gold	-25	+85	°C
T _a	Operating Temperature Diamond	-40	+85	°C
T _{st}	Storage Temperature	-40	+85	°C

PRODUCT ORDERING INFORMATION

PN	Type	Capacity	Technology	Temp range
SDU1GGPGRB	microSD	1 GB	pSLC	-25°C — 85°C
SDU2GGPGRB	microSD	2 GB	pSLC	-25°C — 85°C
SDU4GGPGRB	microSD	4 GB	pSLC	-25°C — 85°C
SDU8GGPGRB	microSD	8 GB	pSLC	-25°C — 85°C
SDU16GGPGRB	microSD	16 GB	pSLC	-25°C — 85°C
SDU32GGPGRB	microSD	32 GB	pSLC	-25°C — 85°C
SDU64GGPGRB	microSD	64 GB	pSLC	-25°C — 85°C
SDU1GDPGRB	microSD	1 GB	pSLC	-40°C — 85°C
SDU2GDPGRB	microSD	2 GB	pSLC	-40°C — 85°C
SDU4GDPGRB	microSD	4 GB	pSLC	-40°C — 85°C
SDU8GDPGRB	microSD	8 GB	pSLC	-40°C — 85°C
SDU16GDPGRB	microSD	16 GB	pSLC	-40°C — 85°C
SDU32GDPGRB	microSD	32 GB	pSLC	-40°C — 85°C
SDU64GDPGRB	microSD	64 GB	pSLC	-40°C — 85°C

PHYSICAL DIMENSION

Dimensions: 15mm (L) * 11mm (W) * 1mm (H)



STANDARDS & REFERENCES

The following table is to list out the standards that have been adopted for designing the product.

STANDARD USED	ACRONYM/SOURCE
RoHS	Restriction of Hazardous Substances Directive
SD specification	http://www.sdcard.org
CE	Consumer electronics certification; please contact us for further information.

SAFETY PRECAUTIONS

Do not bend, crush, drop, or place heavy objects on top of the Product. Do not use tweezers, pliers or similar items that could damage the Product. Take particular care when inserting or removing the Product. Stop using the Product when the Product does not work properly. Failure to follow these instructions could result in fire, damage to the Product and/or other property, and/or personal injury including burns and electric shock.

Keep out of reach of small children. Accidental swallowing may cause suffocation or injury. Contact a doctor immediately if you suspect a child has swallowed the Product.

Do not directly touch the interface pins, put them in contact with metal, strike them with hard objects or cause them to short. Do not expose to static electricity.

Do not disassemble or modify the Product. This may cause electric shock, damage to the Product or fire.

NOTES ON USAGE

The Product contains nonvolatile semiconductor memory. Do not use the Product in accordance with a method of usage other than that written in the manual. This may cause the destruction or loss of data.

To protect against accidental data loss, you should back up your data frequently on more than one type of storage media. Wilk Elektronik S.A. assumes no liability for destruction or loss of data recorded on the Card for any reason.

When used over a long period of time or repeatedly, the reading, writing and deleting capabilities of the Product will eventually fail, and the performance speed of the Product may decrease below the original speed specific to the Product's applicable class.

If the Product is to be transferred or destroyed, note that the data it contained may still be recoverable unless it is permanently deleted by third-party deletion software or similar means beforehand.

Product is intended for use in general electronics applications and selected industrial applications and any other specific applications as expressly stated in this document. Product is neither intended nor warranted for use in equipment or systems where failure may cause loss of human life, bodily injury, serious property damage or serious public impact ("Unintended Use"). Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment or equipment used to control combustions or explosions. Do not use Product for Unintended Use unless specifically permitted in this document.

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